D cket N .: 9733.845.00

Declaration, Power of Attorney and Petition

WB (I) the undersigned inventor(s), hereby declare(s) that:

My residence, post office address and offizenship are as stated below next to my name,

We (I) believe that we me (I am) the original, first, and joint (sole) inventor(s) of the subject matter which is claimed and for which a patent is sought on the invention entitled

METHOD FOR FORMING SEAL PATTERN OF LIQUID CRYSTAL DISPLAY DEVICE

the specification of which

is attached her	ero.		
was filed on		3	
	88 Application No.	1	
	and amended on	1	
was filed as Po	CT international application		
Number		 	
On	Y Y	;	
and was amend	ed under PCT Arricle 19		F
On		(if applicable).	
	was filed as Po Number On and was amend	88 Application No. and amended on was filed as PCT international application Number On and was amended under PCT Arricle 19	88 Application No. and amended on was filed as PCT international application Number On and was amended under PCT Article 19

We (I) hereby state that we (I) have reviewed and understand the contents of the above-identified specification including the claims, as amended by any amendment referred to above.

We (I) acknowledge the duty to disclose information known to be material to the patentability of this application as defined in Section 1.56 of Title 37 Code of Federal Regulations.

We (I) hereby claim foreign priority benefits under 15 U.S.C. §119(a)-(d) or §365(b) of any foreign application(s) for parent or inventor's certificate, or §365(s) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, ony foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed. Prior Foreign Application(s)

Application No.	Country	Day/Month/Year	Priority Claimed			
2002-0074818	Korea	28 November 2002	E	Yes		No
			, 0	Yes		No
				Yes		No
	7.3.1			You.		No

DC-124698 1

2003-JUN-19 16:03

TEL 1954

10)KIMS INTL

PAGE: 003 R=95%

We (I) hereby plaim the benefit under Title 35, United States Code, §119(e) of any United States provisional application(a) listed below.

(Application Number)

(Filing Date)

We (I) hereby claim the benefit under 35 U.S.C. §120 of any United States application(s), or §365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of 35 U.S.C. §112, I seknowledge the duty to disclose information which is material to patentability as defined in 37 CER §1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application.

Application Serial No.	Filing Date	Status (pending, pen	ented, abandoned)
	19		

And we (I) heroby appoint Song E. Jung, Reg. No. 35,210; Matthew T. Bailey, Rog. No. 33,829; Brie J. Nuss, Rog. No. 40,106; Rebessa Goldman Rudich, Reg. No. 41,786; Teresa M. Arroyo, Rog. No. 50,015 as our (my) attempts, with full powers of substitution and revocation, to prosecute this application and to transact all business in the Patent Office connected therewith; and we (I) hereby request that all correspondence regarding this application he sent to Song E. Jung of McKenna Long & Aldridge LLP, Attorneys At Law, 1900 K Street, N.W., Washington, D.C. 20006.

We (I) declare that all statements made herein of our (my) own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Strik 2d 10'40	Residence: Doosing Park Sangga 20	71,407.				
NAME OF FIRST INVENTOR	Tacjcon-dong, Puk-gu. Tacgu-kwangyokahi					
1 11 1	Котеа					
the to the	Citizen of: Republic of Korea					
Signature of Inventor	Post Office Address: Same as abo	ve :				
2005 6. 19						
Date	1					
Soo Min KWAK	Residence: Booyoung APT. 108-14	10, 141,				
NAME OF FIRST INVENTOR	Imgri, Seokjeok-myun, Chilgok-gun Kyongsangbuk-do, Korea					
A VANK	Citizen of: Republic of Korca					
Signature of Inventor	Post Office Address:					
6.19						
Date						

2

DC:124699.1

2003-JUN-19 16:03

TEL)054

JUNIAS INTE

PAGE: 004 R=95%